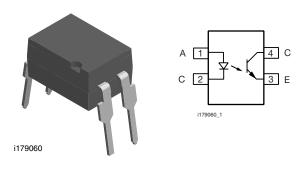


Vishay Semiconductors

Optocoupler, Phototransistor Output, High Reliability, 5300 V_{RMS}



DESCRIPTION

The SFH615XXX features a large assortment of current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

The couplers are end-stackable with 2.54 mm lead spacing. Creepage and clearance distances of > 8 mm are achieved with option 6. This version complies with 60950 (DIN VDE 0805) for reinforced insulation up to operation voltage of 400 V_{RMS} or DC.

FEATURES

- Low CTR degradation
- Good CTR linearity depending on forward current
- Isolation test voltage, 5300 V_{RMS}
- High collector emitter voltage, $V_{CEO} = 70 \text{ V}$
- Low saturation voltage
- Fast switching times
- Temperature stable
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode interference immunity (unconnected base)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

AGENCY APPROVALS

- UL1577
- cUL
- DIN EN 60747-5-5 (VDE 0884) available with option 1
- BSI

ORDERING INFORMATION								
PART NUMBER PACKAGE OPTION								
AGENCY		СТ	R (%)					
CERTIFIED/PACKAGE		5	mA					
UL, cUL, BSI, FIMKO	50 to 600	100 to 600	100 to 300	50 to 150				
DIP-4	SFH615AA	SFH615AGB	SFH615AGR	SFH615AY				
DIP-4, 400 mil, option 6	SFH615AA-X006	-	-	-				
SMD-4, option 7	SFH615AA-X007	-	SFH615AGR-X007T	SFH615AY-X007T				
SMD-4, option 8	-	-	SFH					
SMD-4, option 9	-	SFH615AGB-X009T	-	SFH615AY-X009T (1)				
UL, cUL, VDE, BSI, FIMKO	50 to 600	100 to 600	100 to 300	50 to 150				
DIP-4	SFH615AA-X001	-	SFH615AGR-X001	-				
DIP-4, 400 mil, option 6	-	-	SFH615AGR-X016	SFH615AY-X016				
SMD-4, option 7	SFH615AA-X017T ⁽¹⁾	-	SFH615AGR-X017T ⁽¹⁾	-				
SMD-4, option 8	-	-	-	SFH615AY-X018T (1)				
SMD-4, option 9	-	-	-	SFH615AY-X019T (1)				

Notes

Additional options may be possible, please contact sales office

⁽¹⁾ Also available in tubes; do not add T to end



1



ROHS COMPLIANT



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V _R	6	V			
DC forward current		I _F	60	mA			
Surge forward current	t _P ≤ 10 ms	I _{FSM}	2.5	А			
Power dissipation		P _{diss}	100	mW			
OUTPUT							
Collector emitter voltage		V _{CEO}	70	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		Ic	50	mA			
Collector current	t _P ≤ 10 ms	Ι _C	100	mA			
Total power dissipation		P _{diss}	150	mW			
COUPLER							
Isolation test voltage between emitter and detector		V _{ISO}	5300	V _{RMS}			
Creepage distance			≥7	mm			
Clearance distance			≥7	mm			
Isolation thickness between emitter and detector Comparative tracking index per DIN IEC 112/VDE 0303, part 1		СТІ	≥ 175				
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω			
	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹¹	Ω			
Storage temperature range		T _{stg}	-55 to +150	°C			
Ambient temperature range		T _{amb}	-55 to +100	°C			
Soldering temperature ⁽¹⁾	max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm	T _{sld}	260	°C			

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT		•			•	•	•
Forward voltage	I _F = 60 mA		V _F	-	1.25	1.65	V
Reverse current	V _R = 6 V		I _R	-	0.01	10	μA
Capacitance	V _R = 0 V, f = 1 MHz		Co	-	13	-	pF
Thermal resistance			R _{thja}	-	750	-	K/W
OUTPUT							
Collector emitter capacitance	$V_{CE} = 5 V$, f = 1 MHz		C _{CE}	-	5.2	-	pF
Thermal resistance			R _{thja}	-	500	-	K/W
Collector emitter saturation voltage	I _F = 10 mA, I _C = 2.5 mA		V _{CEsat}	-	0.25	0.4	V
Coupling capacitance			C _C	-	0.4	-	pF
COUPLER							
	V _{CEO} = 10 V	SFH615AA	I _{CEO}	-	10	100	nA
Collector emitter leakage		SFH615AGB	I _{CEO}	-	10	100	nA
current		SFH615AGR	I _{CEO}	-	10	100	nA
		SFH615AY	I _{CEO}	-	10	100	nA

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.



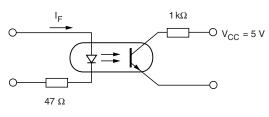
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CURRENT TRANSFER RATIO								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
I _C /I _F	I _F = 5 mA, V _{CE} = 5 V	SFH615AA	CTR	50	-	600	%	
		SFH615AGB	CTR	100	-	600	%	
		SFH615AGR	CTR	100	-	300	%	
		SFH615AY	CTR	50	-	150	%	

SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Turn-on time	I _F = 5 mA	t _{on}	-	2	-	μs	
Turn-off time	I _F = 5 mA	t _{off}	-	25	-	μs	

TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)



isfh615aa_01

_/_C _/_F

Fig. 1 - Switching Operation (with saturation)

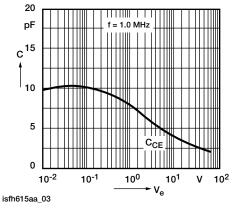


Fig. 3 - Transistor Capacitance (typ.) vs. Collector Emitter Voltage

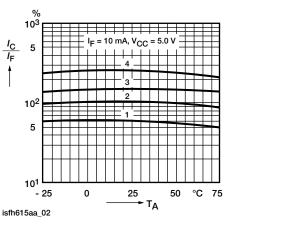


Fig. 2 - Current Transfer Ratio (typ.) vs. Temperature

120 mA 90 60 30 0 75 → T_A 0 25 50 °C 100 isfh615aa_04

Fig. 4 - Permissible Diode Forward Current vs. Ambient Temperature



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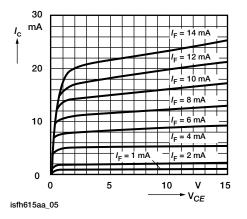


Fig. 5 - Output Characteristics (typ.) Collector Current vs. Collector Emitter Voltage

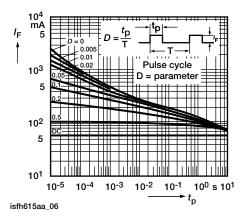


Fig. 6 - Permissible Pulse Handling Capability Forward Current vs. Pulse Width

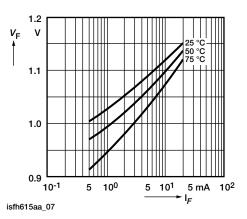


Fig. 7 - Diode Forward Voltage (typ.) vs. Forward Current

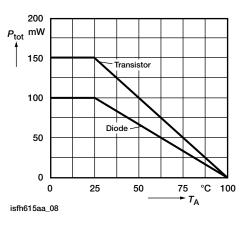


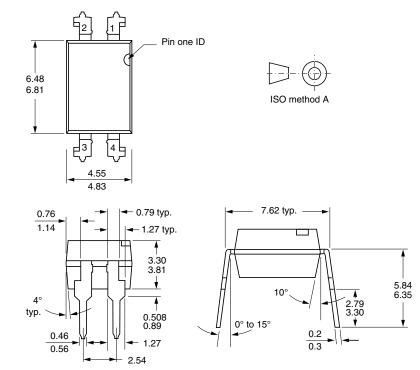
Fig. 8 - Permissible Power Dissipation vs. Temperature



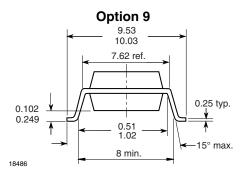
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PACKAGE DIMENSIONS in inches (millimeters)



i178027





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